

## Power Supply IC Series for TFT-LCD Panels

# Gamma voltage generated IC with built-in DAC

**BD81026MUV**
**General Description**

The feature of gamma voltage generated IC BD81026MUV provides a single-chip solution with a high-precision 10-bit DAC setting controlled by I<sup>2</sup>C serial communications interface and a buffer amp (12ch).

**Key Specifications**

- Power Supply Voltage Range(VDD): 2.1V to 3.6V
- Power Supply Voltage Range(VCC): 8.0V to 18.0V
- Operating Temperature Range: -25°C to +85°C

**Features**

- Built in 10bit DAC (12ch)
- Built in DAC Output Buffer Amplifier (12ch)
- Double Register Switch Synchronously Function (BKSEL)
- DAC Output Latch Function (LD)
- I<sup>2</sup>C Interface (SDA, SCL)  
STANDARD-MODE, FAST-MODE changeable
- Thermal Shut-Down Circuit
- Under Voltage Lock-Out Function
- Power ON Reset Circuit
- Input Tolerant ( SDA, SCL, BKSEL, LD )

**Applications**

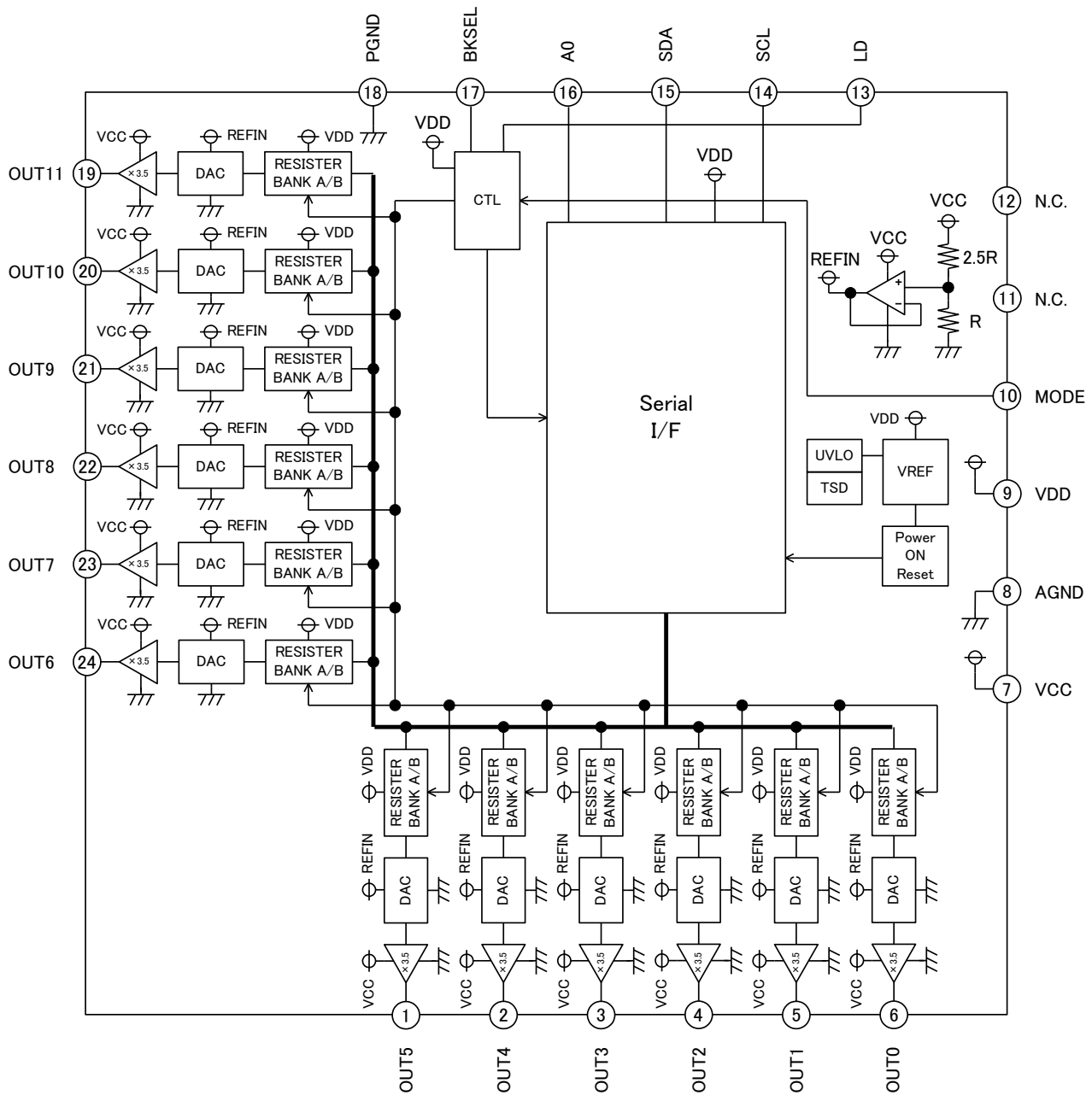
It may be used with TFT-LCD panels, such as big screen and high resolution LCD televisions.

**Package**

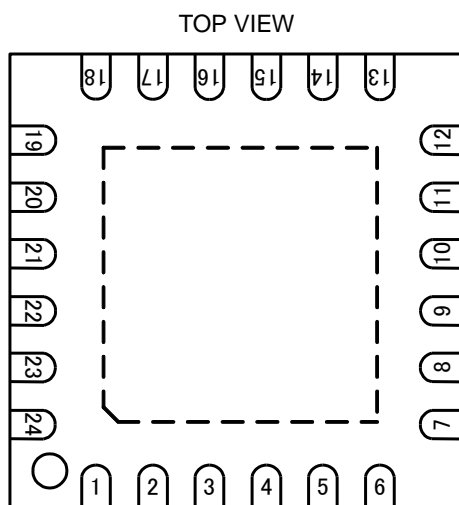
W(Typ) x D(Typ) x H(Max)



## Block Diagram



## Pin Configuration



## Pin Description

PIN No.	Pin name	Function	PIN No.	Pin name	Function
1	OUT5	Gamma output pin 5	13	LD	Latch pin (Note 1)
2	OUT4	Gamma output pin 4	14	SCL	Serial clock input pin
3	OUT3	Gamma output pin 3	15	SDA	Serial data input pin
4	OUT2	Gamma output pin 2	16	A0	Device address switching pin
5	OUT1	Gamma output pin 1	17	BKSEL	BANK select pin (Note 2) L : BANK A select H : BANK B select
6	OUT0	Gamma output pin 0	18	PGND	DAC output buffer amplifier GND input
7	VCC	Buffer amplifier power supply input for DAC output	19	OUT11	Gamma output pin 11
8	AGND	Logic, Analog GND input	20	OUT10	Gamma output pin 10
9	VDD	Logic, Analog power supply input	21	OUT9	Gamma output pin 9
10	MODE	BKSEL/LD mode switching pin L : BKSEL writing mode select H : LD writing mode select	22	OUT8	Gamma output pin 8
11	N.C.	-	23	OUT7	Gamma output pin 7
12	N.C.	-	24	OUT6	Gamma output pin 6

(Note 1) When Data writing function by LD pin control is not used, please connect LD pin to GND.

(Note 2) When Data writing function by BKSEL pin control is not used, please connect BKSEL pin to GND.

**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage 1	V <sub>DD</sub>	4.5	V
Power Supply Voltage 2	V <sub>CC</sub>	19.0	V
Functional Pin Voltage	V <sub>BKSEL</sub> , V <sub>A0</sub> , V <sub>LD</sub> V <sub>MODE</sub>	4.5	V
2 Lines Serial Pin Voltage	V <sub>SDA</sub> , V <sub>SCL</sub>	4.5	V
Junction Temperature	T <sub>jmax</sub>	150	°C
Power Dissipation	P <sub>d</sub>	3.56 (Note 1)	W
Operating Temperature Range	T <sub>opr</sub>	-25 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

(Note 1) To use the IC at temperatures over Ta=25°C, derate power rating by 28.5mW/°C.

When mounted on a four-layer glass epoxy board measuring 74.2mm x 74.2mm x 1.6mm (All layer with copper foil: 5505mm<sup>2</sup>).

**Caution:** Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

**Recommended Operating Conditions** (Ta=-25°C to +85°C)

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage 1	V <sub>DD</sub>	2.1	3.6	V
Power Supply Voltage 2	V <sub>CC</sub>	8.0	18.0	V
Function Pin Voltage	V <sub>BKSEL</sub> , V <sub>A0</sub> , V <sub>LD</sub> V <sub>MODE</sub>	-0.1	+3.6	V
2 Lines Serial Pin Voltage	V <sub>SDA</sub> , V <sub>SCL</sub>	-0.1	+3.6	V
2 Lines Serial Frequency	f <sub>CLK</sub>	-	400	kHz

**Electrical Characteristics** (Unless otherwise specified, Ta=25°C, V<sub>DD</sub>=3.3V, V<sub>CC</sub>=12.6V)

Parameter	Symbol	Limit			Unit	Condition
		MIN	TYP	MAX		
【 Gamma Amplifier 】						
Sink Current Capability Nch Side (AMP0)	IooA	-	-	-10	mA	During REG0=3AFh (11.6V ) setting, VOUT0=12.6V input
Sink Current Capability Nch Side (AMP1 to AMP5, AMP7 to AMP10)	IooB	-	-	-30	mA	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, VOUT1 to VOUT5, VOUT7 to VOUT10=7V
Sink Current Capability Nch Side (AMP6)	IooC	-	-	-60	mA	During REG6=1E8h (6.0V) setting, VOUT6=7V
Sink Current Capability Nch Side (AMP11)	IooD		-	-60	mA	During REG11=051h (1.0V) setting, VOUT11=2V input
Source Current Capability Pch Side (AMP0)	IoiA	60	-	-	mA	During REG0=3AFh (11.6V) setting, VOUT0=10.6V input
Source Current Capability Pch Side (AMP1 to AMP5, AMP7 to AMP10)	IoiB	30	-	-	mA	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, VOUT1 to VOUT5, VOUT7 to VOUT10=5V
Source Current Capability Pch Side (AMP6)	IoiC	60	-	-	mA	During REG6=1E8h (6.0V) setting, VOUT6=5V
Source Current Capability Pch Side (AMP11)	IoiD	10	-	-	mA	During REG11=051h (1.0V) setting, VOUT11=0V input
Load Stability (OUT0)	ΔVO-A	-	10	70	mV	During REG0=1E8h (6.0V) setting, Io=0mA to -30mA
Load Stability (OUT1 to OUT5, OUT7 to OUT10)	ΔVO-B	-	10	70	mV	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, Io=-15mA to +15mA
Load Stability (OUT6)	ΔVO-C	-	10	70	mV	During REG6=1E8h (6.0V) setting, Io=-15mA to +15mA
Load Stability (OUT11)	ΔVO-D	-	10	70	mV	During REG11=1E8h (6.0V) setting, Io=0mA to +30mA
MAX Output Voltage (OUT0)	VOH-A	VCC-0.2	VCC-0.1	-	V	Io=-30mA
MAX Output Voltage (OUT1 to OUT5, OUT7 to OUT10)	VOH-B	VCC-1.0	VCC-0.6	-	V	Io=-15mA
MAX Output Voltage (OUT6)	VOH-C	VCC-1.0	VCC-0.6	-	V	Io=-15mA
MAX Output Voltage (OUT11)	VOH-D	VCC-1.2	VCC-0.75	-	V	Io=-15mA
MIN Output Voltage (OUT0)	VOL-A	-	0.75	1.20	V	Io=+15mA
MIN Output Voltage (OUT1 to OUT5, OUT7 to OUT10)	VOL-B	-	0.6	1.0	V	Io=+15mA
MIN Output Voltage (OUT6)	VOL-C	-	0.6	1.0	V	Io=+15mA
MIN Output Voltage (OUT11)	VOL-D	-	0.1	0.2	V	Io=+30mA
Slew Rate (AMP0)	SR-A	1	4	-	V/μsec	OUT0=No load
Slew Rate (AMP1 to AMP5, AMP7 to AMP10)	SR-B	1	4	-	V/μsec	OUT1 to OUT5,OUT7 to OUT10=No load
Slew Rate (AMP6)	SR-C	1	4	-	V/μsec	OUT6=No load
Slew Rate (AMP11)	SR-D	1	4	-	V/μsec	OUT11=No load

**Electrical Characteristics – Continued** (Unless otherwise specified, Ta=25°C, V<sub>DD</sub>=3.3V, V<sub>CC</sub>=12.6V)

Parameter	Symbol	Limit			Unit	Condition
		MIN	TYP	MAX		
【 10 Bit DAC 】						
Resolution	RES	-	10	-	Bit	
Integral Non-Linearity Error (INL)	LE	-2	-	+2	LSB	005h to 3FAh is the allowable margin of error against the ideal linear.
Differential Non-Linearity Error (DNL)	DLE	-2	-	+2	LSB	005h to 3FAh is the allowable margin of error against the ideal increase of 1LSB.
Output Voltage Precision	V <sub>O</sub>	5.945	6.005	6.065	V	During REG0 to REG11=1E8h (6.0V) setting
Output Voltage Thermal Characteristics	V <sub>T</sub>	-50	-	+50	mV	During REG0 to REG11=1E8h (6.0V) setting, Ta=-25°C to +85°C
【 Control Signal 1 (BKSEL, A0, LD, MODE) 】						
Threshold Voltage 1	V <sub>th1A</sub>	0.8	-	1.7	V	V <sub>DD</sub> =3.3V
Threshold Voltage 2	V <sub>th1B</sub>	0.6	-	1.7	V	V <sub>DD</sub> =2.5V
Pull-down Resistor	R <sub>ctl</sub>	21	30	39	kΩ	
【 Control Signal 2 (SDA, SCL) 】						
Threshold Voltage 1	V <sub>th2A</sub>	0.8	-	1.7	V	V <sub>DD</sub> =3.3V
Threshold Voltage 2	V <sub>th2B</sub>	0.6	-	1.7	V	V <sub>DD</sub> =2.5V
Minimum Output Voltage	V <sub>OCL</sub>	-	-	0.4	V	I <sub>SDA</sub> =3mA
【 Whole Device 】						
VDD Power ON Reset Start-up Voltage	V <sub>det1</sub>	1.75	1.9	2.05	V	VDD Rising voltage
VDD Under Voltage Lock-Out Voltage	V <sub>DDUV</sub>	1.55	1.7	1.85	V	VDD Falling voltage
VDD Under Voltage Lock-Out Hysteresis Voltage	V <sub>DDHY</sub>	-	200	-	mV	
VCC Under Voltage Lock-Out Release Voltage	V <sub>det2</sub>	3.2	3.4	3.6	V	VCC Rising voltage
VCC Under Voltage Lock-Out Voltage	V <sub>CCUV</sub>	2.8	3.0	3.2	V	VCC Falling voltage
VCC Under Voltage Lock-Out Hysteresis Voltage	V <sub>CCHY</sub>	-	400	-	mV	
BKSEL Switching Time (Note 1)	t <sub>BKSEL</sub>	-	0.3	1.0	μsec	
LD Switching Time (Note 2)	t <sub>LD</sub>	-	0.3	1.0	μsec	
VDD Circuit Current	I <sub>CCCL</sub>	0.16	0.25	0.34	mA	Output No-load , DAC initial value setting
VCC Circuit Current	I <sub>CCCH</sub>	2	4	6	mA	Output No-load , DAC initial value setting

(Note 1) BKSEL switching time timing is shown below.

(Note 2) LD switching time timing is shown below.

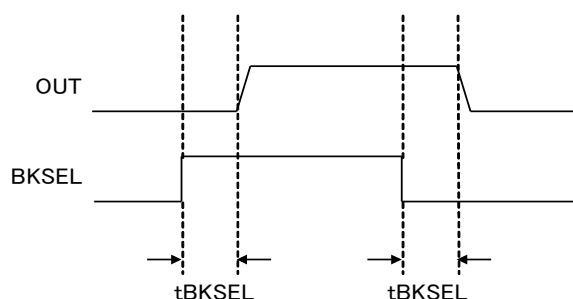


Figure 1. BKSEL Switching time timing

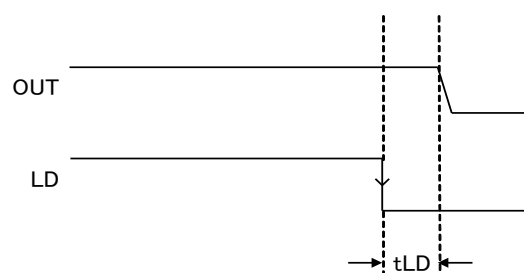


Figure 2. LD Switching time timing

## Operation of each block

### (1) 10 Bit DAC block

#### ■ Serial data control block

The serial interface uses a 2-line serial data format (SCL, SDA).

The serial data control block consists of a register that stores data from the SDA and SCL pins, and a DAC circuit that receives the output from this register and provides adjusted voltages to other IC blocks.

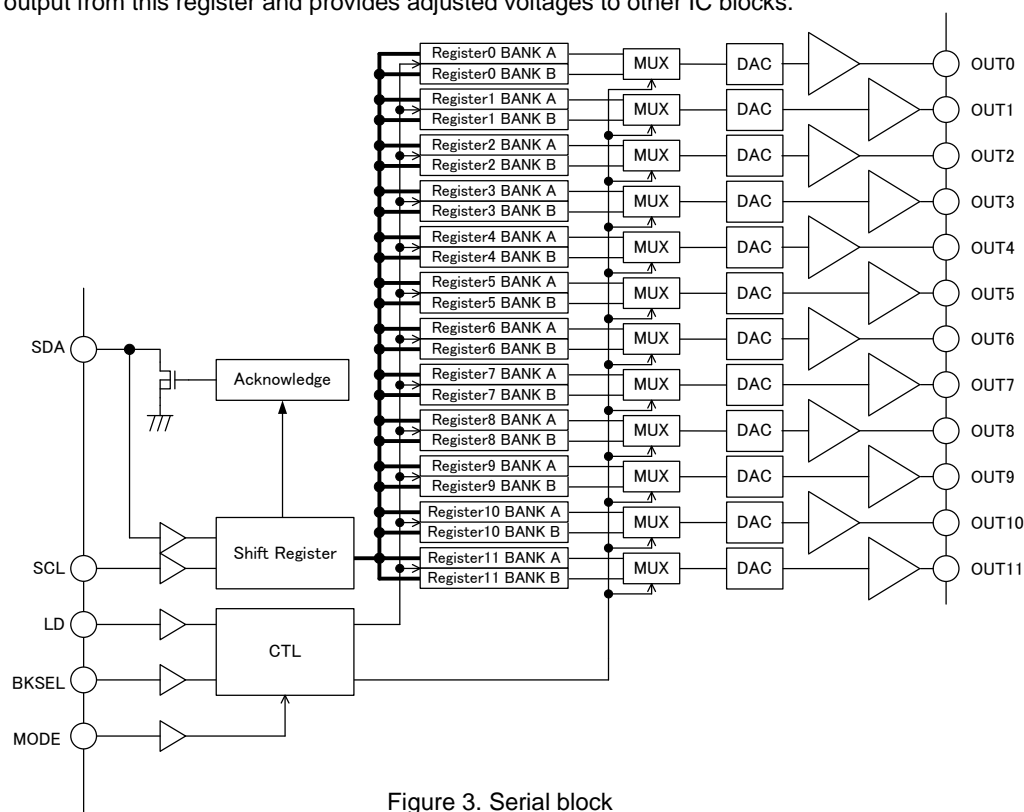


Figure 3. Serial block

#### • Register ( Ch0 to Ch11 )

A serial signal (consisting of 10-bit gamma correction voltage values) input using the serial interface or I<sup>2</sup>C bus interface is held for each register address.

Data is initialized by the reset signal generated during a power-on reset.

Register is selectable by BKSEL pin. (For detail, refer to P.9.)

Also, it is selectable that either revises the DAC output setting voltage by LD pin to the data, read to register. (For detail, refer to P.10.)

#### • Data writing mode selector

Switching MODE pin High/Low enables changing data switching mode.

During MODE=Low, a data is rewrite by Double Register switching function of BKSEL control.

During MODE=High, a data is rewrite by DAC output latch function of LD control.

MODE pin is pulled down inside so that at open state, it is Low.

If it is set to High, connect to VDD.

#### • DAC

The DAC LOGIC converts the 10-bit digital signal read to the register to a voltage.

#### • AMP ( Ch0 to Ch11 )

The Amp amplifies the voltage output from the DAC LOGIC.

While Under Voltage Lock-Out (UVLO) circuit or Thermal Shut Down (TSD) circuit is operating, output goes into Hi-z.

In case connecting high capacity capacitor with low ESR, damping is needed with a resistor to keep phase margin.

■ Output Voltage setting mode

Writes to a register address specified by I<sup>2</sup>C BUS.

Mode for writing from I<sup>2</sup>C BUS to register are ( i )Single mode and ( ii )Multi mode.

On single mode, write data to one designated register.

On multi mode, multi data write can be performed continuously from a start address register specified with the second byte of data.

Single mode or multi mode can be configured by having or not having “stop bit”.

(i) Single mode timing chart

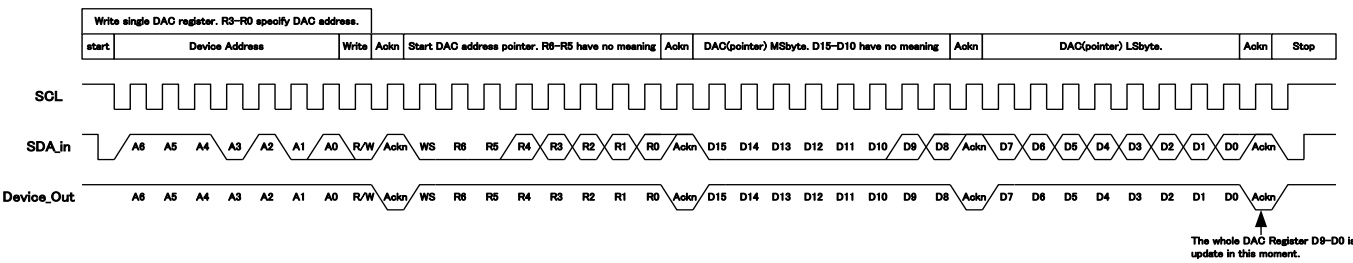


Figure 4. Output voltage setting (Single mode)

(ii) Multi mode timing chart

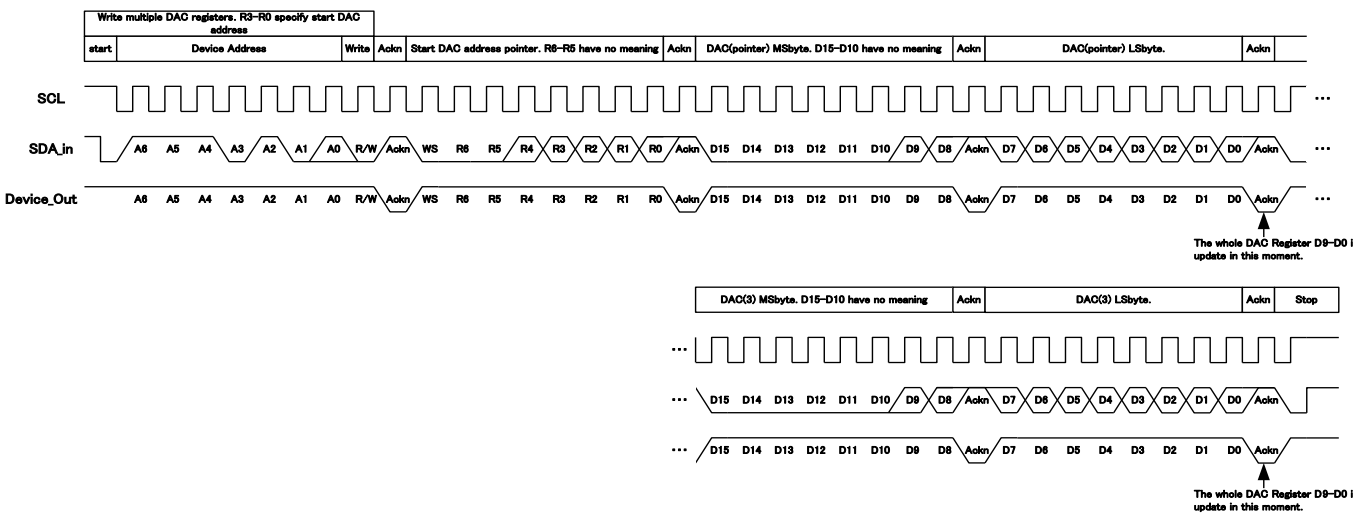


Figure 5. Output voltage setting (Multi mode)

■ Device address

Device address A6 to A1 are specific to the IC and should be set as follows: (A6 to A0) =111010(A0).

A0 can be set by external. It is pulled-up inside so that in open state, it turns to "0". If setting to "1", connect to VDD.

### ■ Command interface


Use I<sup>2</sup>C BUS for command interface with host. Writing or reading by specifying 1 byte select address, along with slave address. I<sup>2</sup>C BUS Slave mode format is shown below.

	MSB	LSB		MSB	LSB		MSB	LSB	
S	Slave Address		A	Select Address		A	DATA		P

- S : START condition
- Slave Address : After slave address (7bit), send total 8bit data with either READ mode (H) or WRITE mode (L). (MSB first)
- A : Acknowledge  
Added acknowledge bit per byte in sending and receiving data.  
If the data is sent/ received properly, "L" is send/ received.  
Sending or Receiving "H" means lack of acknowledge.
- Select Address : Use 1 byte select address.
- DATA : Data byte. Sending/ Receiving data. (MSB first)
- P : STOP condition

The case where writing 3FCh to DAC1 (Single mode)

S	Slave Address	A	Select Address	A	Register1 DATA0	A	Register1 DATA1	A	P
(EX.)	E8h or EAh		01h		03h		FCh		

 : Slave from master       : Master from slave

The case where writing 3FCh from DAC0 to DAC3 (Multi mode)

S	Slave Address	A	Select Address	A	Register0 DATA0	A	Register0 DATA1	A	Register1 DATA0	A	Register1 to 3 DATA0,DATA1	A	P
(EX.)	E8h or EAh		00h		03h		FCh		03h				

 : Slave from master       : Master from slave

### ■ Double Register switching function

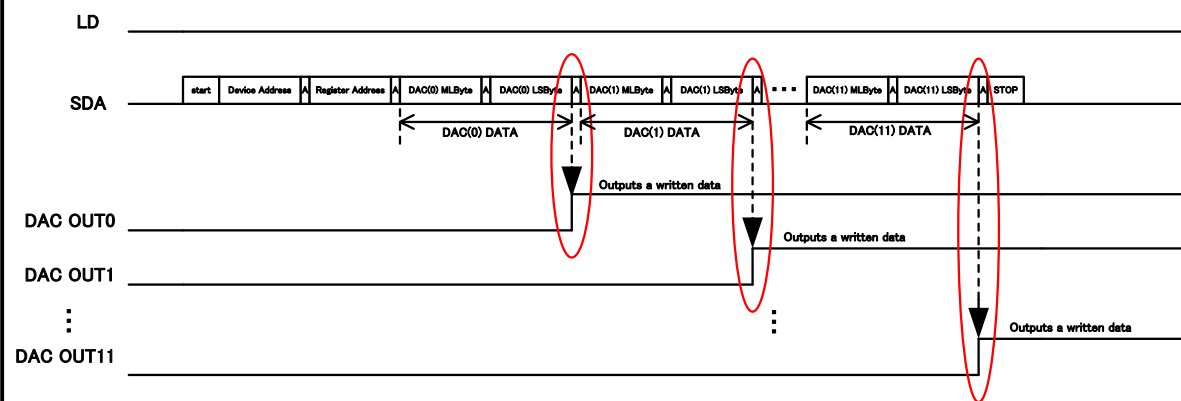
When setting Low of MODE pin, it is able to switch BANK A or BANK B by changing High/Low of BKSEL pin.  
During BKSEL=Low, connect BANK A to DAC.  
During BKSEL=High, connect BANK B to DAC.

### ■ DAC output switching function by LD pin

During MODE pin = High setting, depending on LD pin condition, DAC output is able to switch.

- In case LD=Low, write a data to a register of a specified address and DAC output outputs the data written to the register.  
(Refer to Figure 6: DAC output switching operation by LD pin (i).)
- In case LD=High, write a data to a register of a specified address and DAC output maintains the previous data setting. In this condition, if LD pin switches from High to Low, all DAC output (OUT0 to OUT11) outputs synchronously a data, written to a register.  
(Refer to Figure 6: DAC output switching operation by LD pin (ii).)

#### ( i ) When LD = Low, DAC output switching operation



#### ( ii ) When LD = High, DAC output switching operation

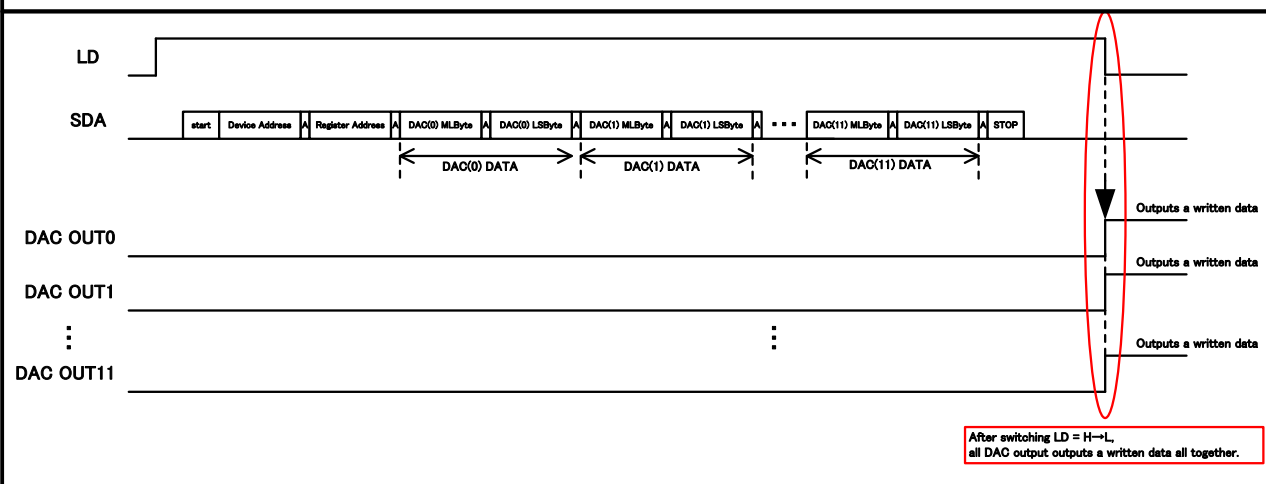


Figure 6. DAC output switching operation by LD pin

### ■ Register address

BANK A and BANK B register addresses are configured by the chart below.

Register name	BANK A					Initial Value	Register name	BANK B					Initial Value
	R4	R3	R2	R1	R0			R4	R3	R2	R1	R0	
Register 0 BANK A	0	0	0	0	0	000h	Register 0 BANK B	1	0	0	0	0	000h
Register 1 BANK A	0	0	0	0	1	000h	Register 1 BANK B	1	0	0	0	1	000h
Register 2 BANK A	0	0	0	1	0	000h	Register 2 BANK B	1	0	0	1	0	000h
Register 3 BANK A	0	0	0	1	1	000h	Register 3 BANK B	1	0	0	1	1	000h
Register 4 BANK A	0	0	1	0	0	000h	Register 4 BANK B	1	0	1	0	0	000h
Register 5 BANK A	0	0	1	0	1	000h	Register 5 BANK B	1	0	1	0	1	000h
Register 6 BANK A	0	0	1	1	0	000h	Register 6 BANK B	1	0	1	1	0	000h
Register 7 BANK A	0	0	1	1	1	000h	Register 7 BANK B	1	0	1	1	1	000h
Register 8 BANK A	0	1	0	0	0	000h	Register 8 BANK B	1	1	0	0	0	000h
Register 9 BANK A	0	1	0	0	1	000h	Register 9 BANK B	1	1	0	0	1	000h
Register 10 BANK A	0	1	0	1	0	000h	Register 10 BANK B	1	1	0	1	0	000h
Register 11 BANK A	0	1	0	1	1	000h	Register 11 BANK B	1	1	0	1	1	000h

For Register address, lower 5bit (R4 to R0) at 2<sup>nd</sup> byte will be used. R6 to R5 is "Don't Care."

### (2) Power On Reset

At VDD input, it generates Reset signal and initialize serial I/F and each register.

### (3) UVLO (Under Voltage Lock Out)

When VDD and VCC falls under the setting value, Under Voltage Lock Out function is activated and output will be Hi-Z.

If VDD UVLO is operated, initialize a register.

If VCC UVLO is operated, NOT initialize a register.

### (4) TSD(Thermal Shut Down)

The TSD circuit turns output Hi-z when the chip temperature reaches or exceeds approximately

175°C in order to prevent thermal destruction or thermal runaway. When the chip returns to a specified temperature, the circuit resets.

The TSD circuit is designed only to protect the IC itself. Application thermal design should ensure operation of the IC below the junction temperature of approximately 150°C.

### Power supply sequence

Activate VDD before VCC to avoid a malfunction due to undefined logic in LOGIC circuit. Inputs serial data after canceling Power on Reset.

In case power supply turns OFF, it is recommended after VCC OFF, VDD OFF, or VCC and VDD OFF synchronously.

If VDD turns OFF before VCC OFF, output condition may not be stable because of LOGIC circuit instability.

Please demonstrate and test fully on an application board.

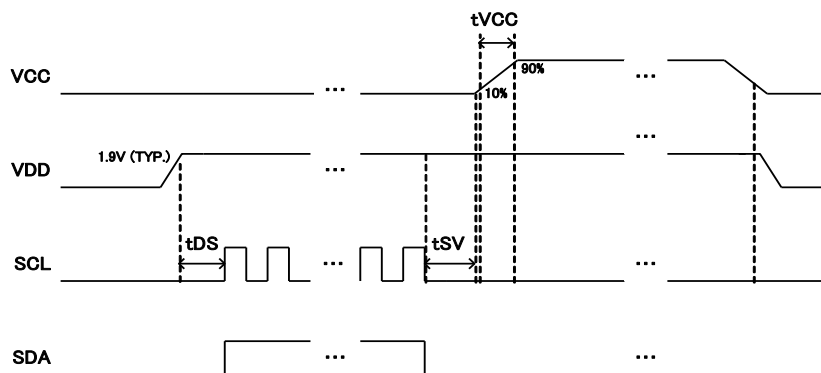
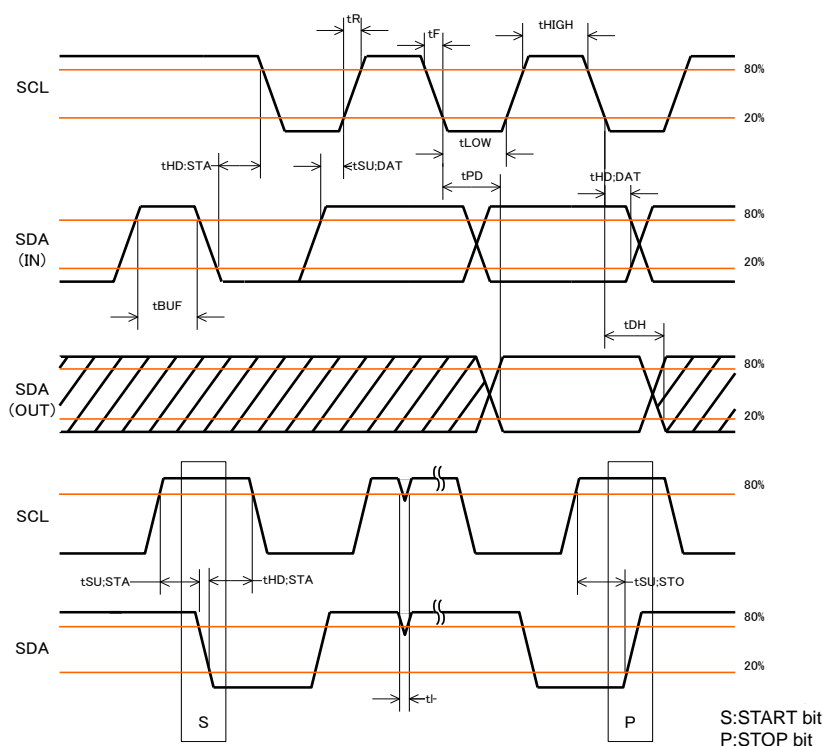


Figure 7. Power supply sequence

### Power supply sequence typical value

Parameter	Symbol	Limit			Unit	Condition
		Min	Typ	Max		
Serial Input Timing	t <sub>DS</sub>	100	-	-	μs	
VCC Input Timing	t <sub>SV</sub>	10	-	-	μs	
VCC Rising Time	t <sub>VCC</sub>	1	-	-	ms	

I<sup>2</sup>C TimingFigure 8. I<sup>2</sup>C timing

## • Timing rule

PARAMETER	SYMBOL	NORMAL mode			FAST mode			Unit
		MIN	TYP	MAX	MIN	TYP	MAX	
SCL frequency	$f_{SCL}$	-	-	100	-	-	400	kHz
SCL "H" time	$t_{HIGH}$	4.0	-	-	0.6	-	-	$\mu s$
SCL "L" time	$t_{LOW}$	4.7	-	-	1.2	-	-	$\mu s$
Rising time	$t_R$	-	-	1.0	-	-	0.3	$\mu s$
Falling time	$t_F$	-	-	0.3	-	-	0.3	$\mu s$
Start condition holding time	$t_{HD,STA}$	4.0	-	-	0.6	-	-	$\mu s$
Start condition set-up time	$t_{SU,STA}$	4.7	-	-	0.6	-	-	$\mu s$
SDA holding time	$t_{HD,DAT}$	200	-	-	100	-	-	ns
SDA set-up time	$t_{SU,DAT}$	200	-	-	100	-	-	ns
Acknowledge delay time	$t_{PD}$	-	-	0.9	-	-	0.9	$\mu s$
Acknowledge hold time	$t_{DH}$	-	0.1	-	-	0.1	-	$\mu s$
Stop condition set-up time	$t_{SU,STO}$	4.7	-	-	0.6	-	-	$\mu s$
BUS open time	$t_{BUF}$	4.7	-	-	1.2	-	-	$\mu s$
Noise spike width	$t_I$	-	0.1	-	-	0.1	-	$\mu s$

## Gamma output setting

Relation between gamma output voltage (OUT0 to OUT11) and DAC setting value is shown as below.

$$\text{Output voltage (OUT0 to OUT11)} = \frac{\text{DAC setting value}}{1024} \times V_{CC}$$

DAC setting value range is 0 to 1023.

Gamma output OUT0 to OUT11 is outputted after VCC UVLO release. During UVLO detection, output is Hi-Z.

I/O Equivalent circuits

1.OUT5, 2.OUT4, 3.OUT3, 4.OUT2 5.OUT1, 6.OUT0, 19.OUT11, 20.OUT10 21.OUT9, 22.OUT8, 23.OUT7, 24.OUT6	7.VCC	9.VDD
10.MODE, 13.LD, 16.A0, 17.BKSEL	14.SCL	15.SDA

## Operational Notes

### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

### 5. Thermal Consideration

Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

## Operational Notes – continued

**12. Regarding the Input Pin of the IC**

This monolithic IC contains P<sup>+</sup> isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

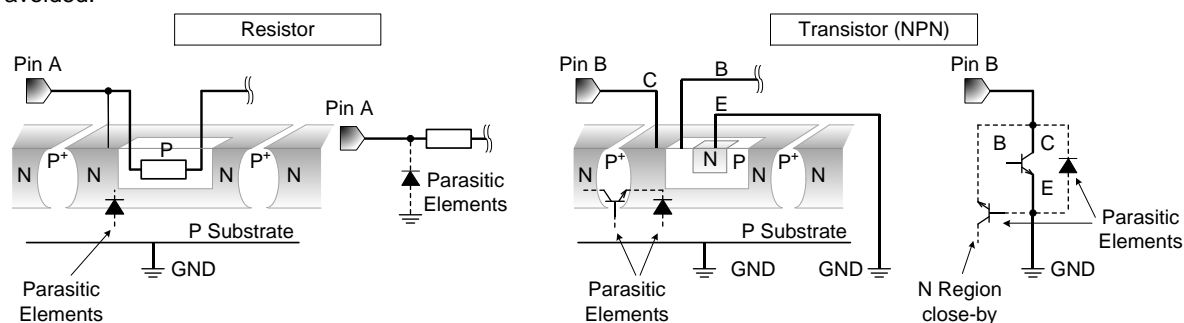


Figure 9. Example of monolithic IC structure

**13. Thermal Shutdown Circuit(TSD)**

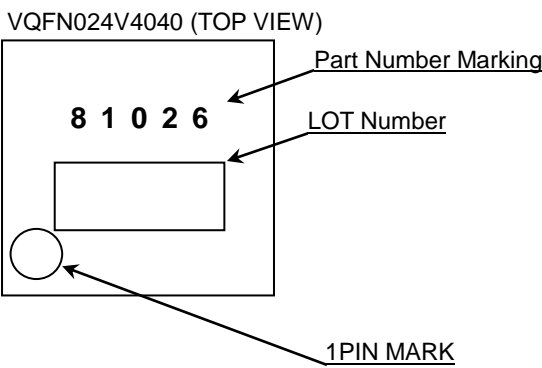
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (T<sub>j</sub>) will rise which will activate the TSD circuit that will turn OFF all output pins. When the T<sub>j</sub> falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

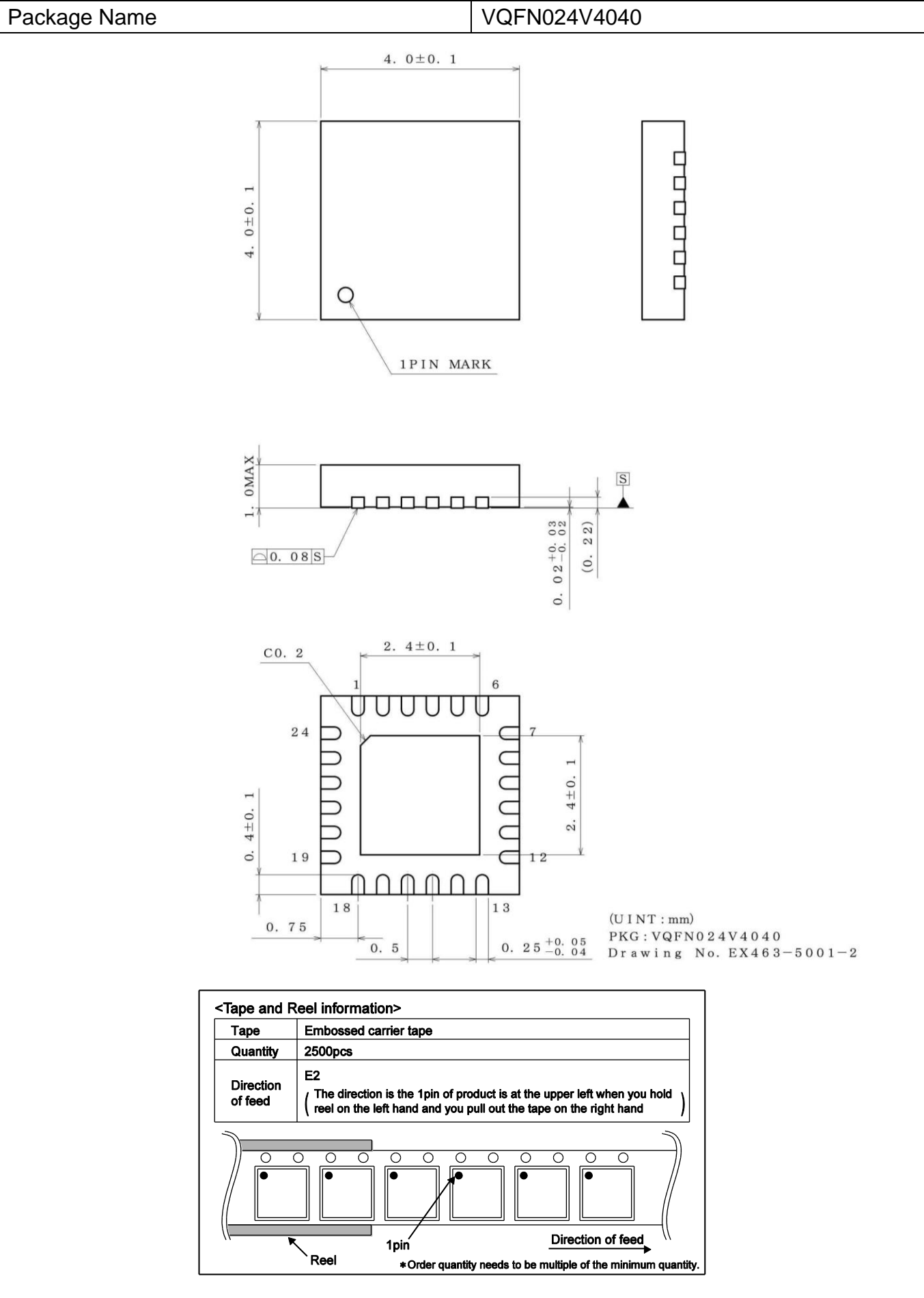
Ordering Information

B D 8 1 0 2 6 M U V										-	E 2
Part number										Package MUV: VQFN024V4040	
Packaging and forming specification E2: Embossed											

Marking Diagram



Physical Dimension, Tape and Reel Information



**Revision History**

Date	Revision	Changes
19.Feb.2016	001	New Release

# Notice

## Precaution on using ROHM Products

- Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

- ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - Installation of protection circuits or other protective devices to improve system safety
  - Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc. prior to use, must be necessary:
  - Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - Sealing or coating our Products with resin or other coating materials
  - Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - Use of the Products in places subject to dew condensation
- The Products are not subject to radiation-proof design.
- Please verify and confirm characteristics of the final or mounted products in using the Products.
- In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## Precaution for Mounting / Circuit board design

- When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

## Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

## Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of ionizer, friction prevention and temperature / humidity control).

## Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

## Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

## Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

## Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

## Precaution Regarding Intellectual Property Rights

1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

## Other Precaution

1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

**General Precaution**

1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ROHM Semiconductor:](#)

[BD81026MUV-E2](#)

## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9